



Negative and Positive Ion Density in front of Negative Ion Production Surface in Large-scaled Negative Ion Source for Fusion

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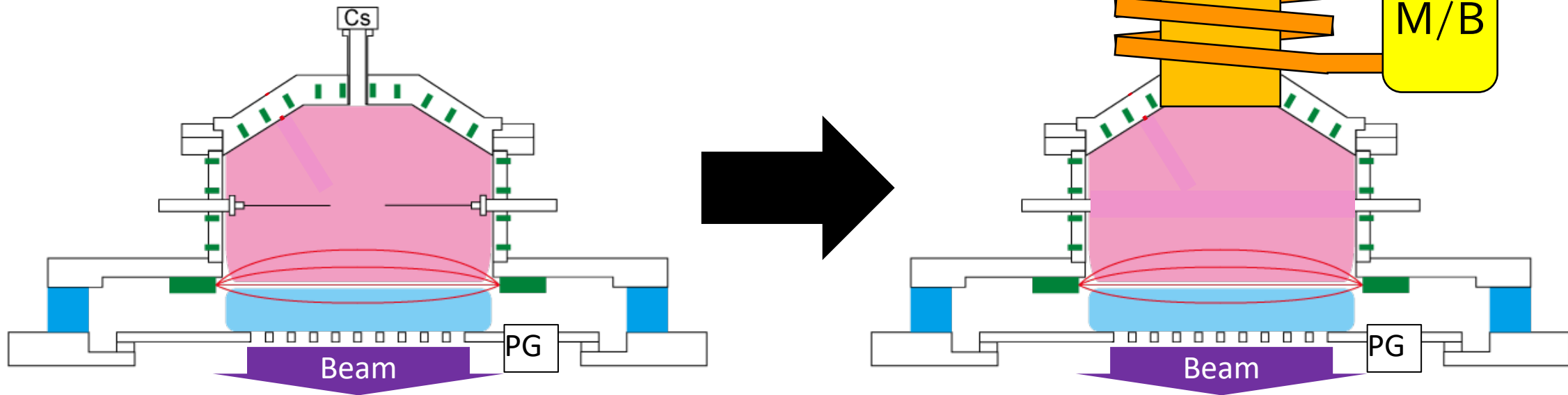
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Negative ion source for fusion



Filament-driven Arc (FA) negative ion source

RF negative ion source

- The RF source is needed for CW operation, however there are tasks for applying actual NBIs.
- FA sources have been applied for actual NBIs on LHD and JT-60. The techniques and physics inside the FA source can contribute to the RF source development.

Objective

<Ion source for fusion>

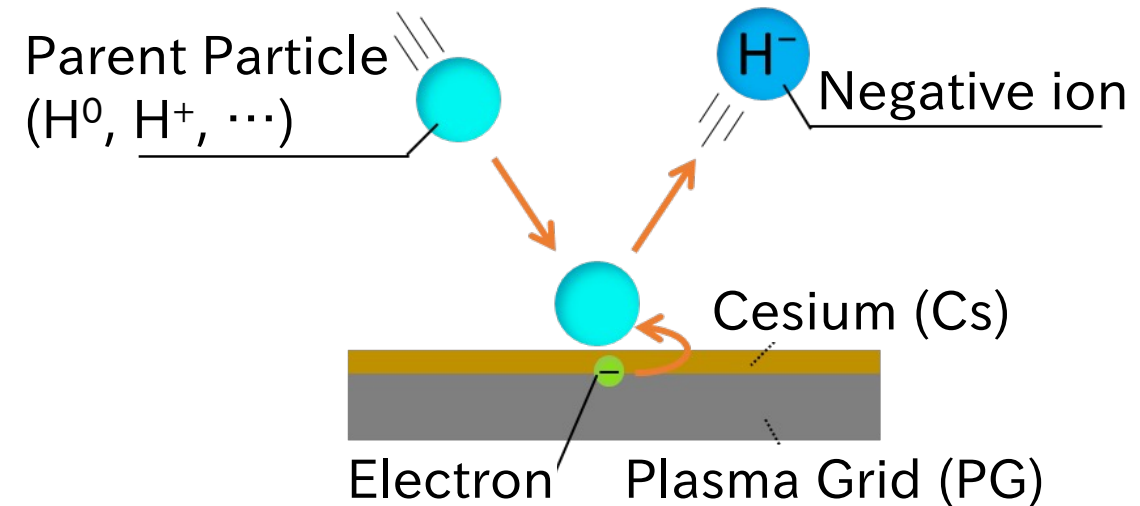
Large scale, cesium seeded, huge power, high energy, and cw (etc.) negative ion source

- Homogeneity, operation stability as well as high beam intensity and low divergence, etc.
- **Surface negative ion production** is dominant.
- Deuterium is utilized. **Isotope effect** exist.

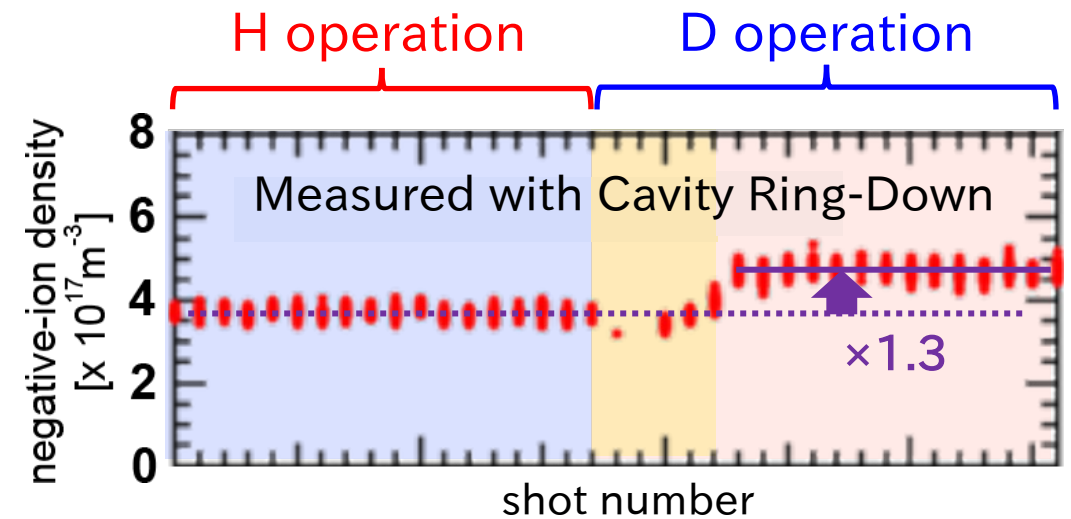
Objective

- Species of parent particle of surface produced negative ion production is identified.
- Understanding of the isotope effect on negative ion density is improved.

Which is dominant parent particle?

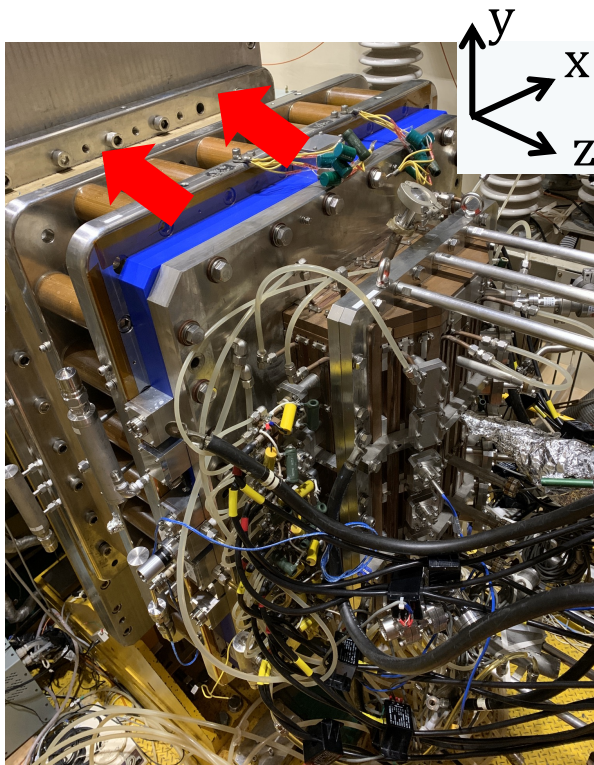


Isotope effect on negative ion density



[H. Nakano+, Jpn. J. Appl. Phys. (2020)]

Experimental Setup (NIFS-RNIS)



Research and development
Negative Ion Source
(NIFS-RNIS)

<Diagnostics>

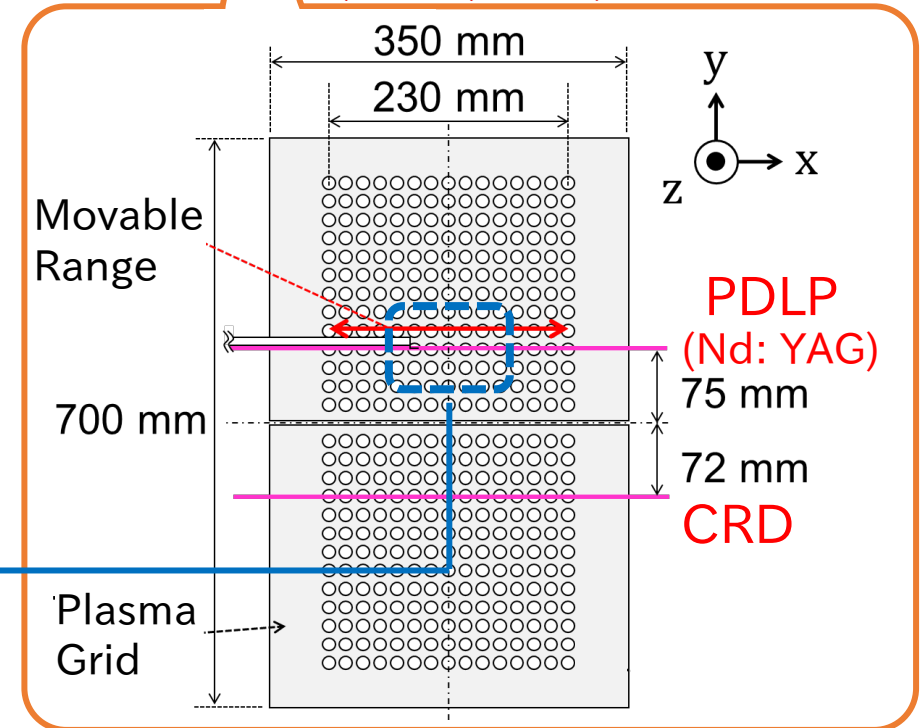
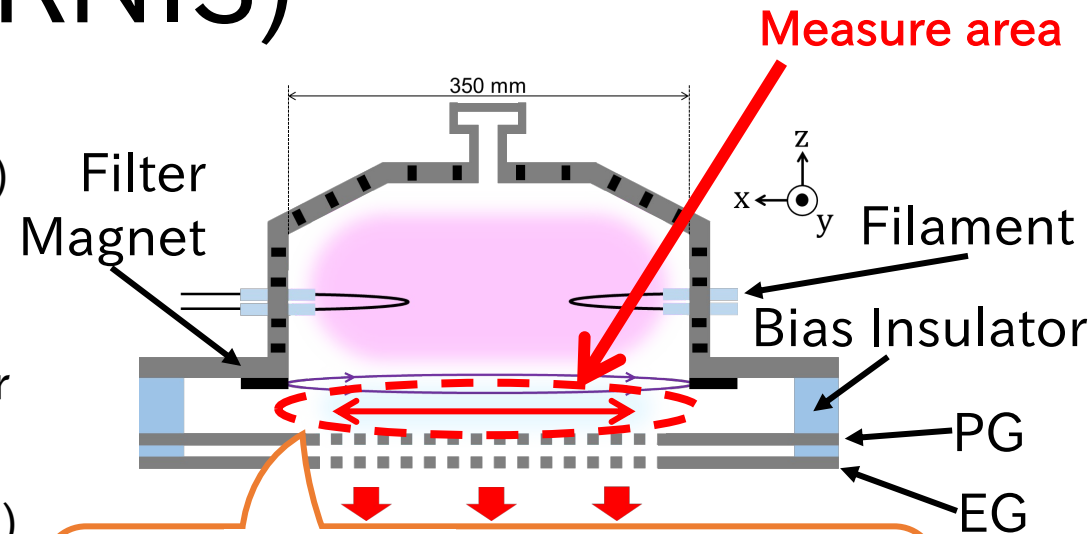
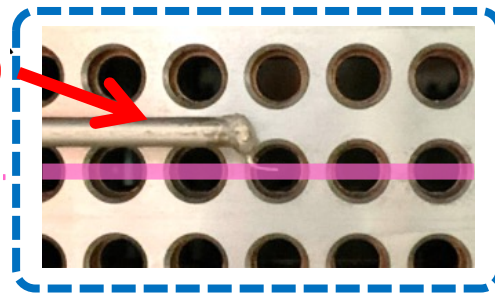
- Cavity RingDown technique (CRD)
 - Line-averaged absolute negative ion density
- Photo-Detachment with Langmuir Probe (PDLP)
 - Local **negative ion** density (n_-) (with CRD support)
 - Local **positive ion** density (n_+)

<Operation cond. >

- Pressure: 0.3 Pa@H₂, D₂
- No beam extraction

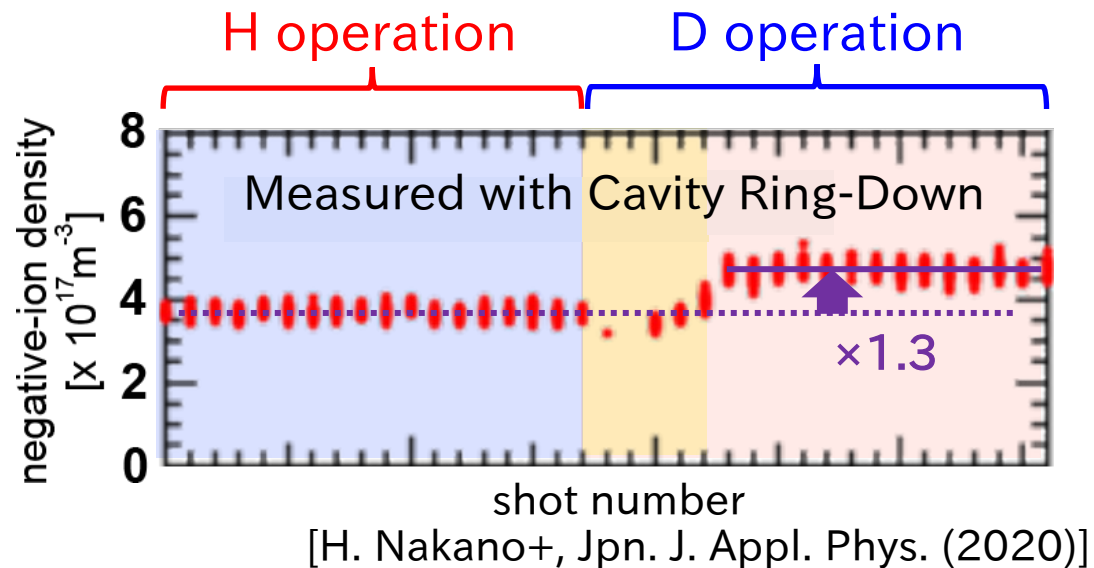
Langmuir Probe (LP)

Nd:YAG laser

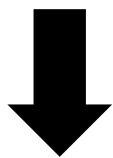


Isotope effect on negative ion density

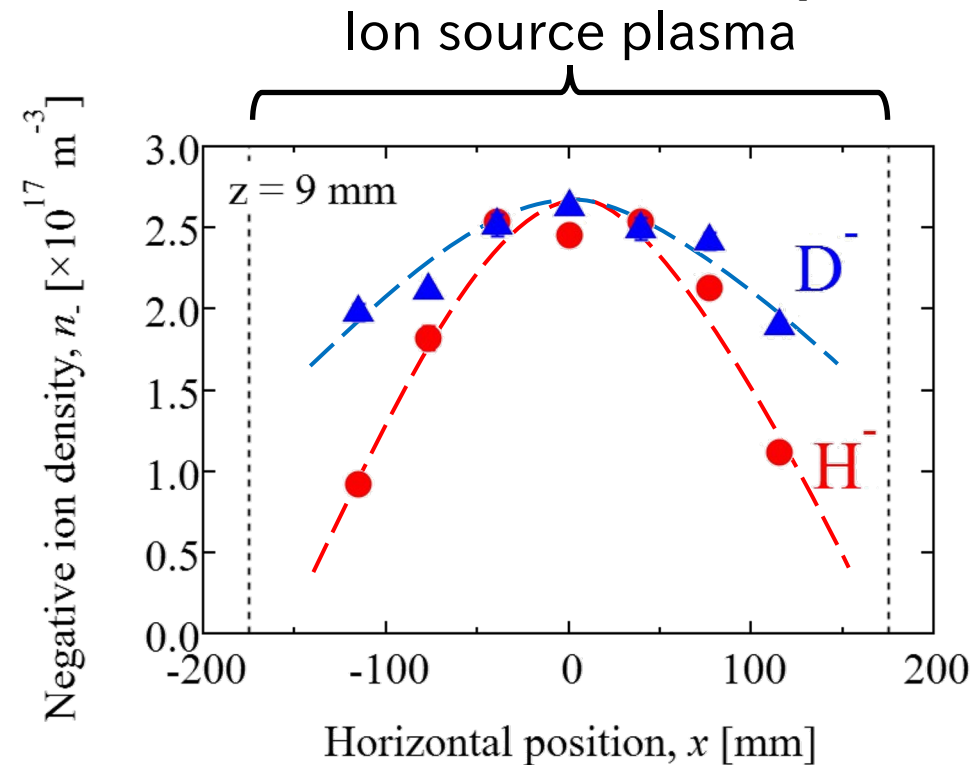
[S. Masaki+, RS (2020)]



Line-averaged $n(H^-)$ was 1.3 times higher than $n(D^-)$.



Because peripheral $n(D^-)$ is higher.

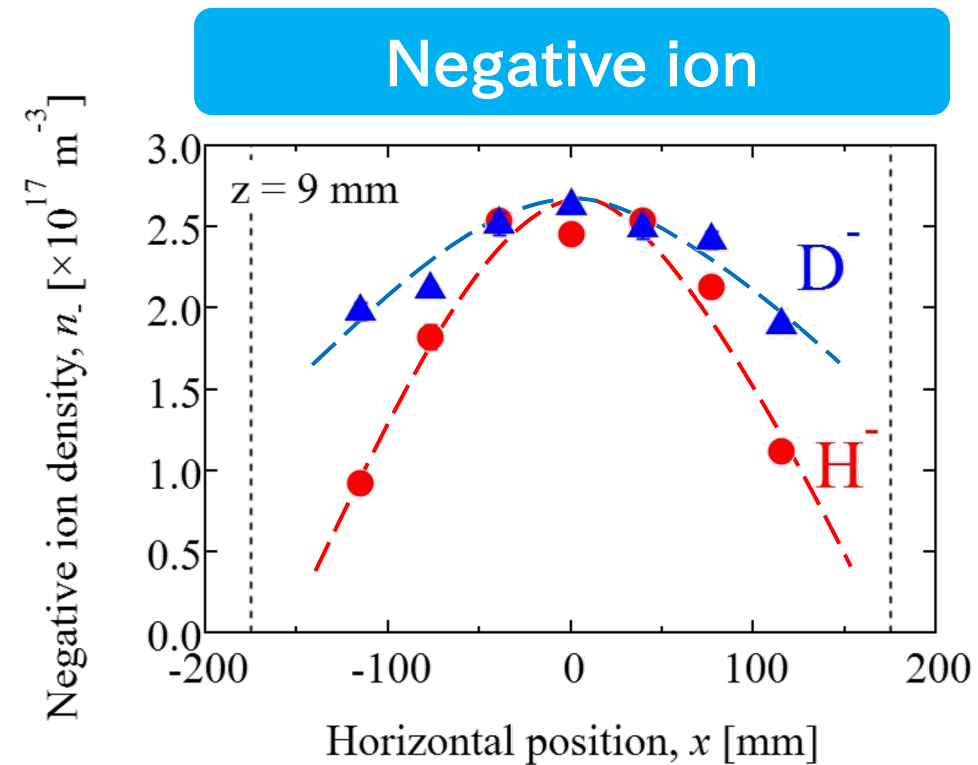
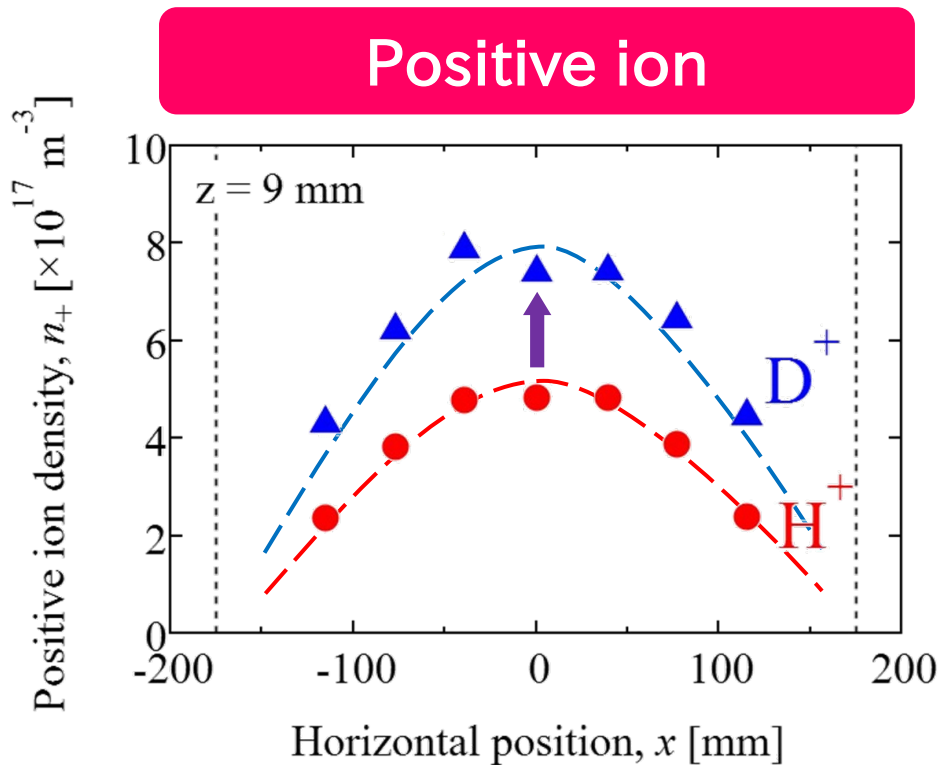


Different n_- was observed between D and H operations.

- Center: $n(D^-) \sim n(H^-)$.
- Periphery: $n(D^-) > n(H^-)$.

Positive ion density profile

[S. Masaki+, Rev. Sci. Instrum. (2020)]



$n(D^+)$ is higher than $n(H^+)$ with the same profile shape.

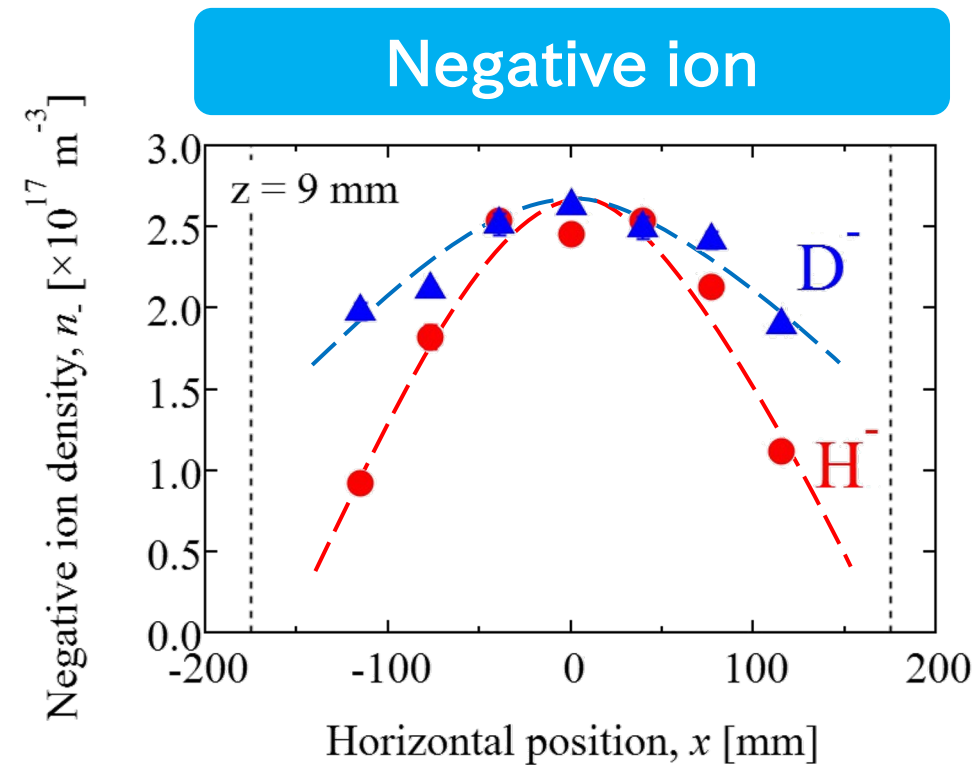
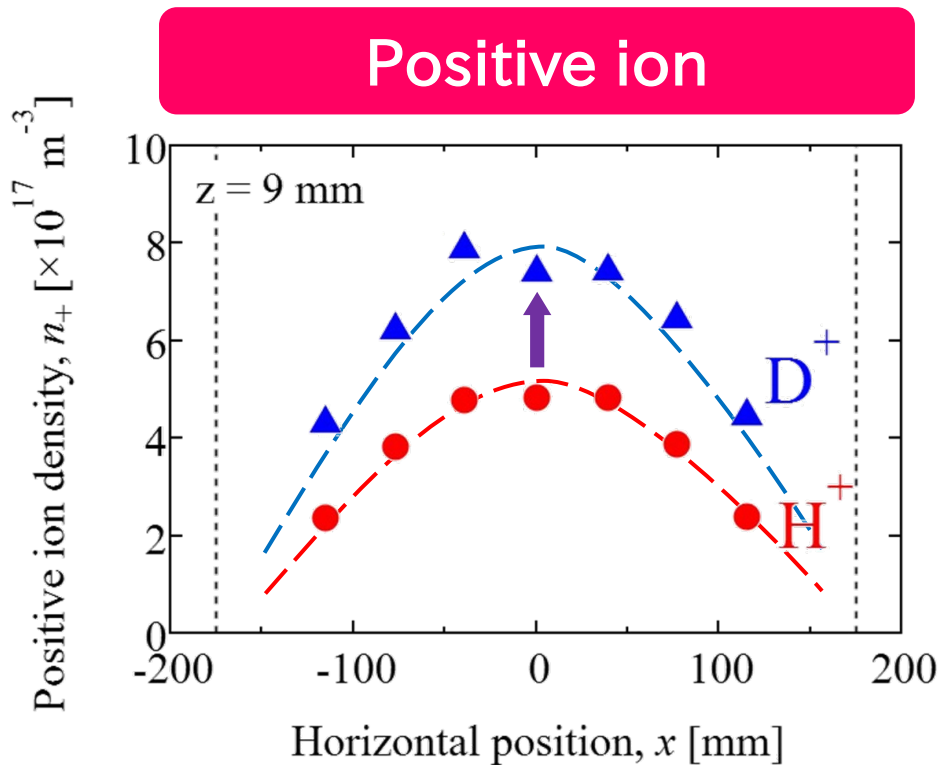
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Why are n_- profile shapes different by isotopes?

Positive ion density profile

[S. Masaki+, Rev. Sci. Instrum. (2020)]

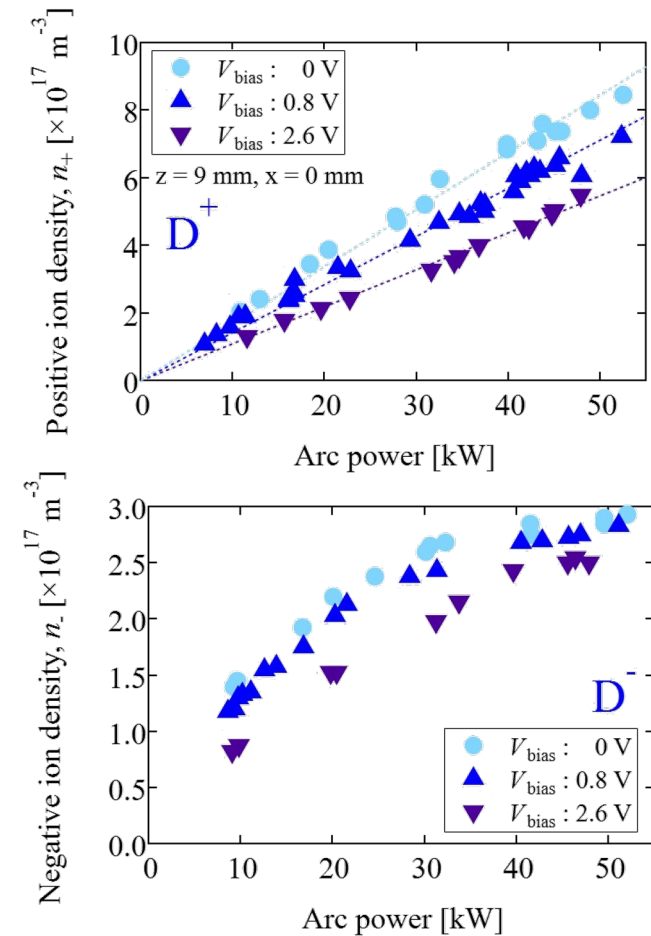
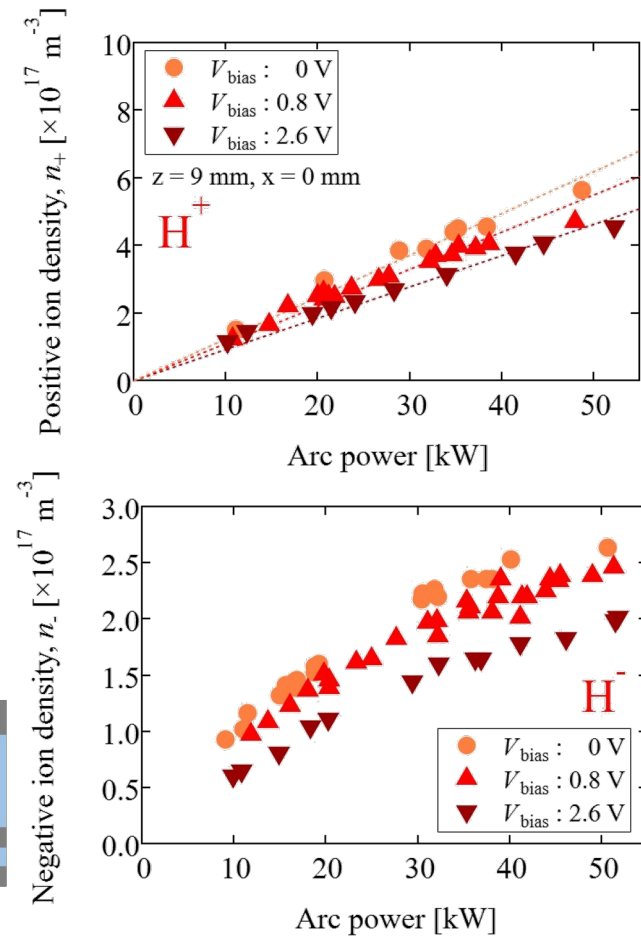
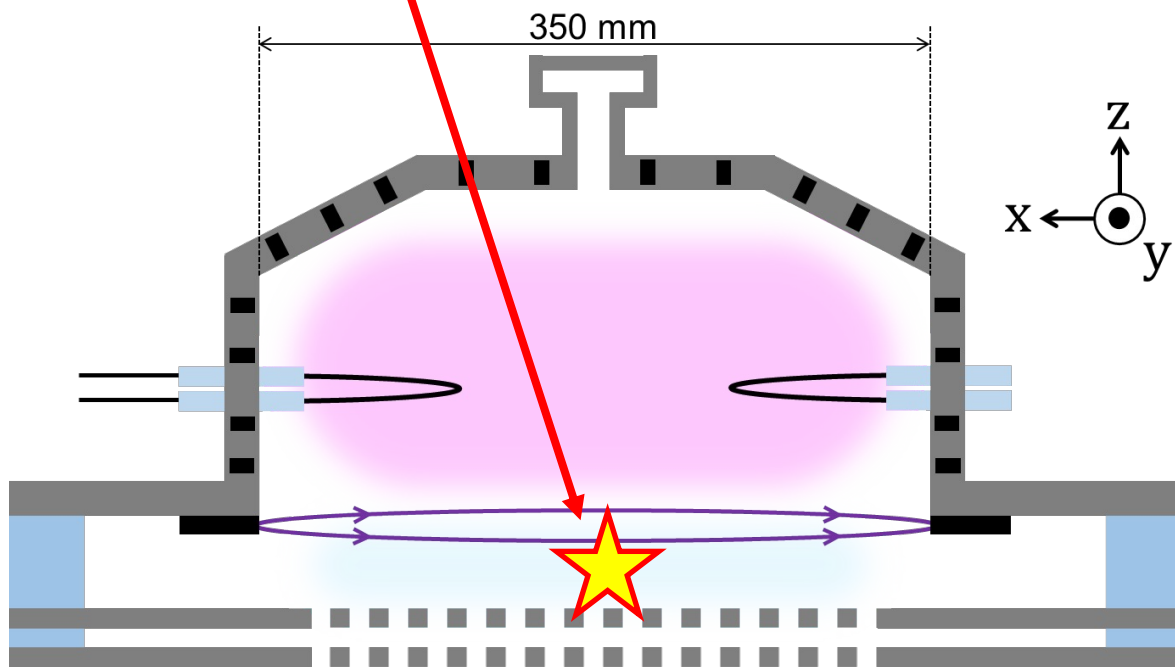


Why are n_- profile shapes different by isotopes?

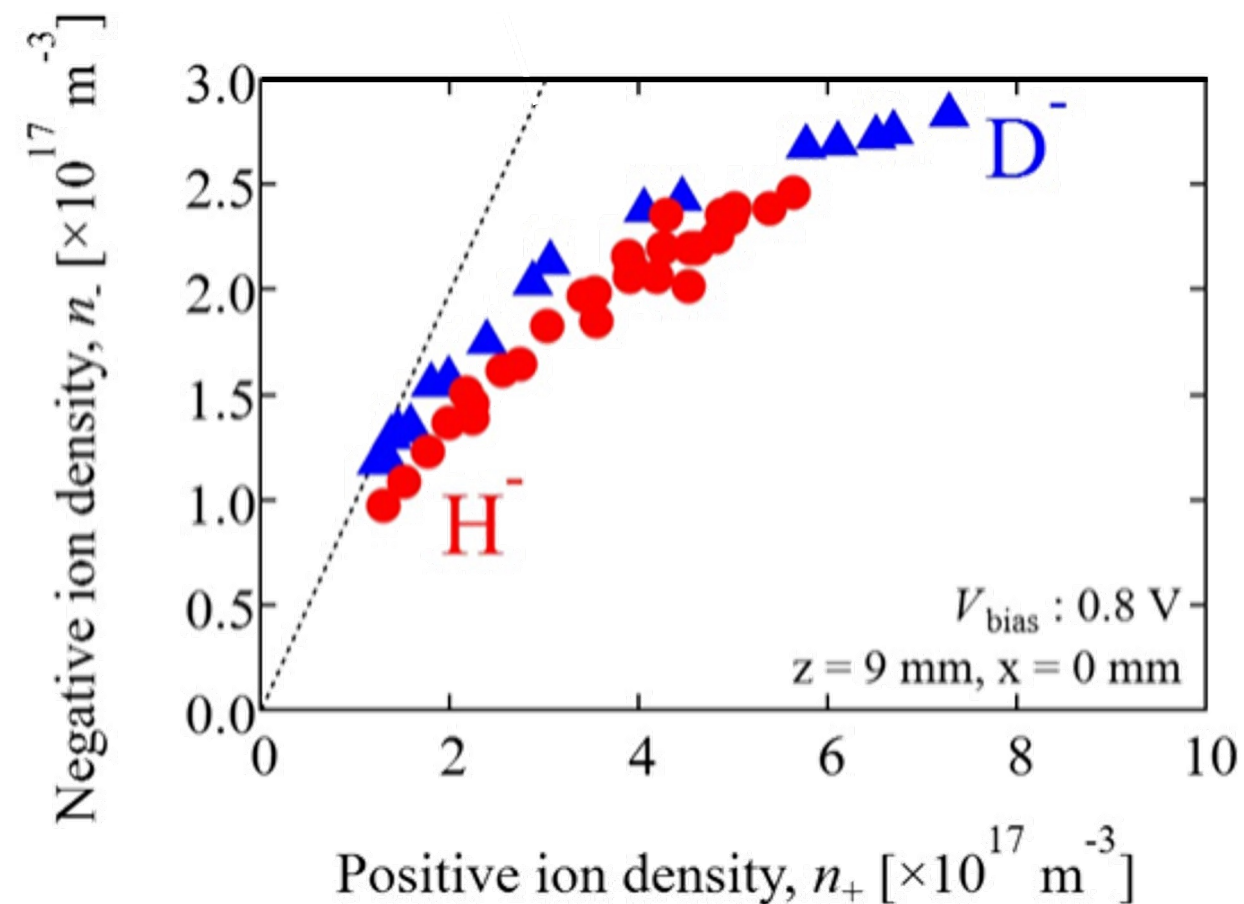
1. Different atom profiles?
 - Local measurement of atom is not easy.
2. Different negative ion production yield by isotopes?
 - Explore relation between positive and negative ions.

Positive and negative ion density as a function of discharge power at horizontal center

Measure density at the horizontal center.



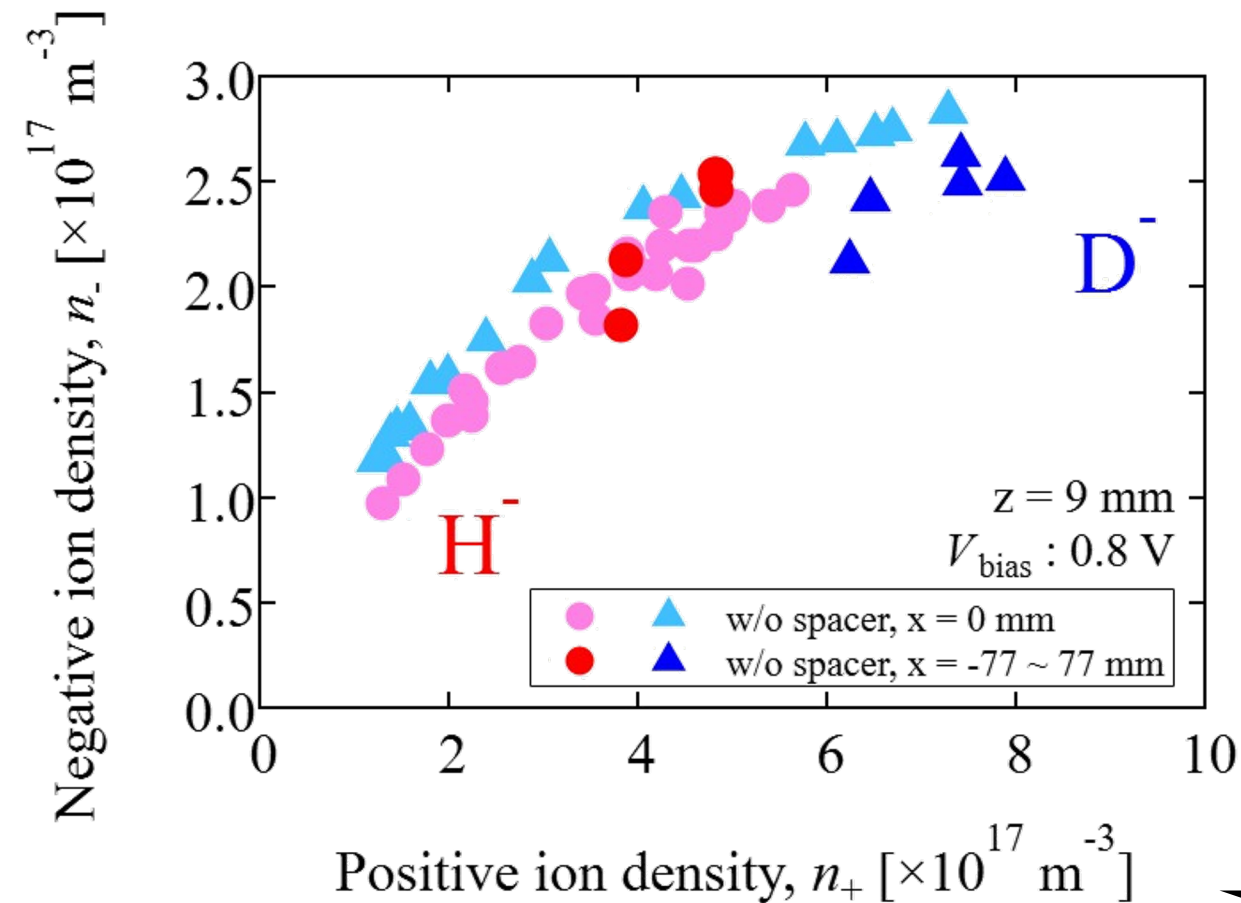
Negative ion ratio to positive ion at horizontal center



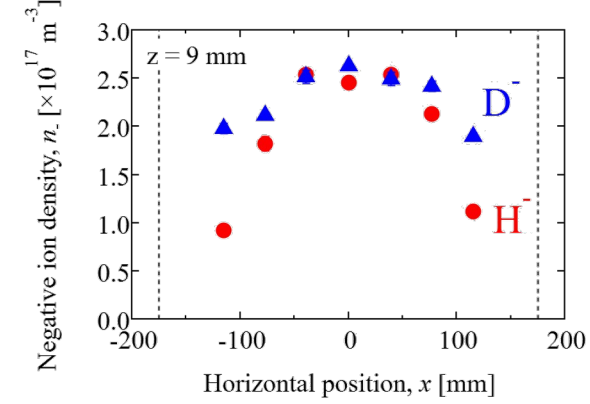
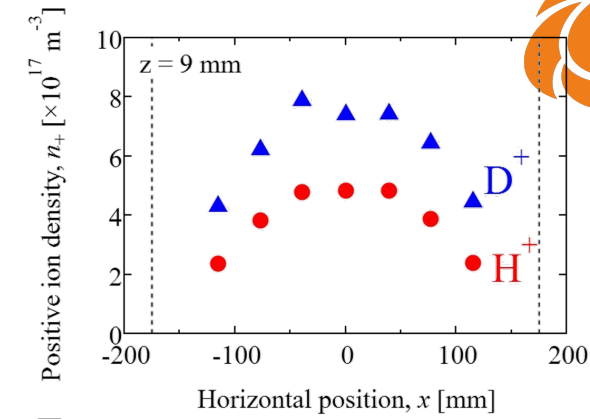
- 1) Increase of n_- degrades for n_+ in both isotope cases.
- 2) Absolute values n_- of the isotopes for n_+ are similar.



Negative ion ratio to positive ion



Combine
Density profile



Points of n_- as a function of n_+ from profile measurements are plotted on the same trend evaluated from data at the center.

Local n_- seems to strongly depends on local n_+ .

$n(D^-) \sim n(H^-)$ at the center caused by the n_- degradation as a function of n_+ in higher n_+ .

Dominant parent particle of surface produced negative ion seems to be positive ion.

Why does the n_- degrade in high n_+ ?

Rate equation for negative ion density

$$\frac{dn_-}{dt} = S - n_-(n_+R_{MN} + n_eR_{ED} + n_nR_{AD}) - \frac{n_-}{\tau}$$

S : Negative ion production rate

τ : Servival time of negative ion

<u>Destruction process</u>	<u>Reaction speed coefficient</u>
➤ Mutual neutralization (MN)	$R_{MN} = \int_0^{\infty} f_+(E)\sigma_{MN}(E)v_+(E)dE$
➤ Electron impact destruction (ED)	$R_{ED} = \int_0^{\infty} f_e(E)\sigma_{ED}(E)v_e(E)dE$
➤ Atomic impact destruction (AD)	$R_{AD} = \int_0^{\infty} f_n(E)\sigma_{AD}(E)v_n(E)dE$

In stationary state ($\frac{dn_-}{dt} = 0$), above equation becomes

$$n_- = \tau \left\{ \underbrace{S}_{\text{Production}} - \underbrace{n_-(n_+R_{MN} + n_eR_{ED} + n_nR_{AD})}_{\text{Destruction}} \right\}$$

Dominant negative ion destruction process

$$n_- = \tau \left\{ \underbrace{S}_{\text{Production}} - \underbrace{\left[n_- (n_+ R_{\text{MN}} + n_e R_{\text{ED}} + n_n R_{\text{AD}}) \right]}_{\text{Destruction}} \right\}$$

Destruction FRQ: f_{MN} , f_{ED} , and f_{AD}

$$\left\{ \begin{array}{l} f_{\text{MN}} \sim 2 \times 10^4 \text{ Hz} @ n_+ \sim 5 \times 10^{17} \text{ m}^{-3}, T_+ \sim 0.3 \text{ eV} \\ f_{\text{ED}} \sim 2 \times 10^3 \text{ Hz} @ n_e \sim 2 \times 10^{17} \text{ m}^{-3}, T_e \sim 0.8 \text{ eV} \\ f_{\text{AD}} \sim 6 \times 10^3 \text{ Hz} @ n_n \sim 5 \times 10^{18} \text{ m}^{-3}, T_n \sim 0.3 \text{ eV, Dissociation Rate: 0.7 in 0.3 Pa (H}_2, \text{D}_2) \end{array} \right.$$

Dominant negative ion destruction process is the mutual neutralization (MN) by **positive ion**.

MN process makes the relation between n_- and n_+ .

$$n_- = \tau \left\{ \underbrace{S}_{\text{Production}} - \underbrace{\left[n_- (n_+ R_{\text{MN}} + n_e R_{\text{ED}} + n_n R_{\text{AD}}) \right]}_{\text{Destruction}} \right\} \sim \tau \{ S - n_- n_+ R_{\text{MN}} \}$$

If the parent particle of negative ion is positive ion, n_- (Production) $\propto n_+$.

$$\tau S \equiv \eta n_+.$$

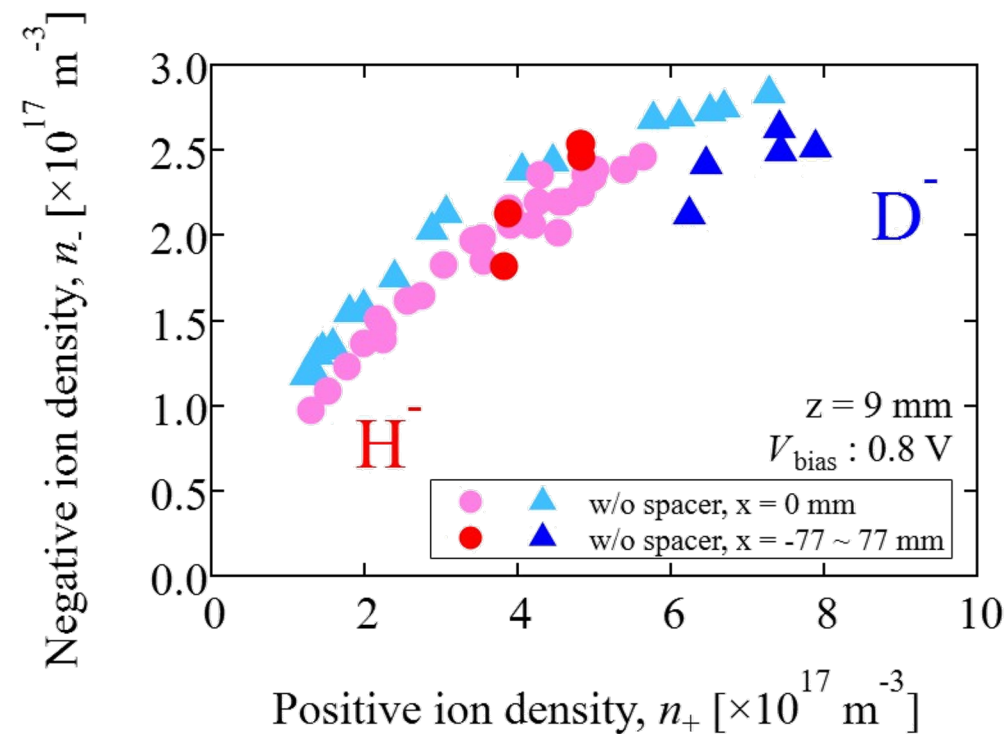
Destruction term can be written by

$$\tau R_{\text{MN}} n_- n_+ = \tau R_{\text{MN}} (\eta n_+) n_+ \equiv \kappa n_+^2.$$

Rate equation is modified by

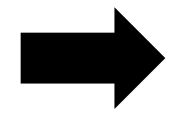
$$n_- = \underbrace{\left[\eta n_+ \right]}_{\text{Production}} - \underbrace{\left[\kappa n_+^2 \right]}_{\text{Destruction}}$$

Degradation of n_- increase with n_+ is caused by mutual neutralization (MN) in high n_+ region if parent particle is positive ion.



Characteristics length of negative ion mortion

$$\begin{cases} \tau S \equiv \eta n_+ \\ \tau R_{MN}(\eta n_+) n_+ \equiv \kappa n_+^2 \end{cases}$$



Negative ion survival time:

$$\tau = \frac{\kappa}{\eta R_{MN}} \sim 2 \times 10^{-5} \text{ [s]}$$

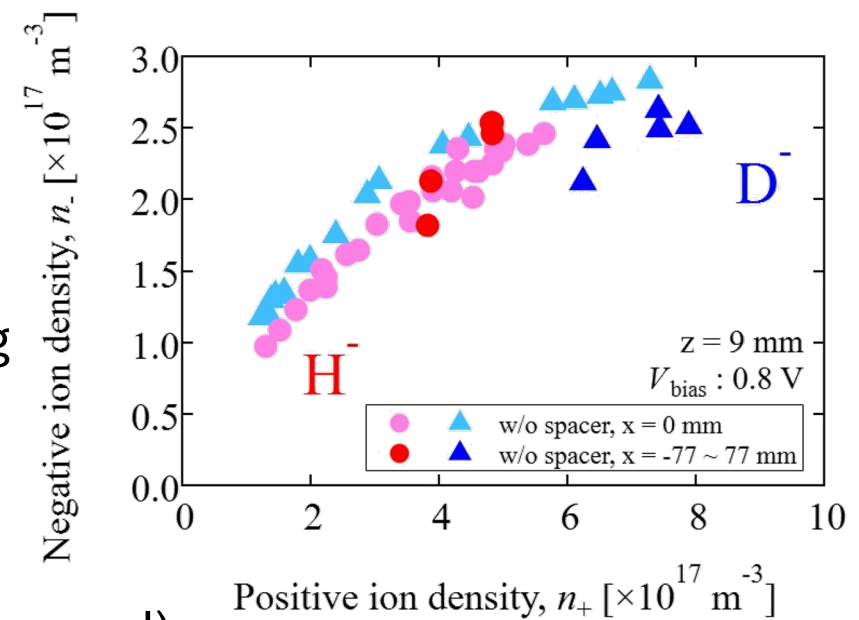
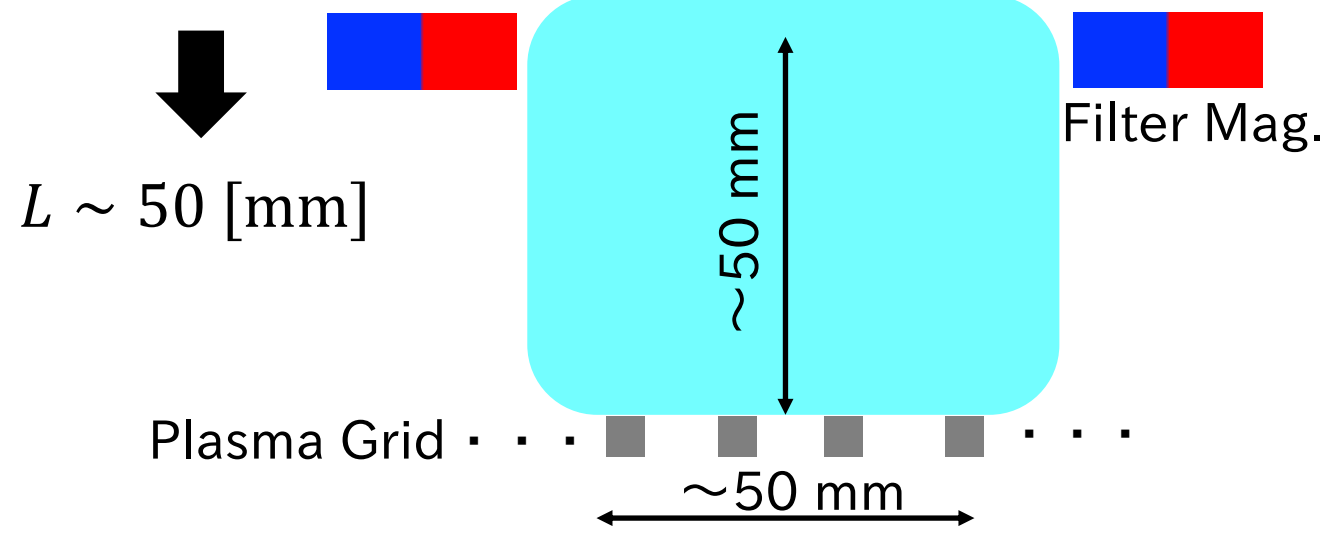
From curve fitting

Negative ion survival time can be also written by

$$\tau \equiv \frac{L}{v_{th-}}$$

L : Characteristic length of negative ion mortion

v_{th-} : Negative ion thermal velocity, ~ 0.1 eV (measured)

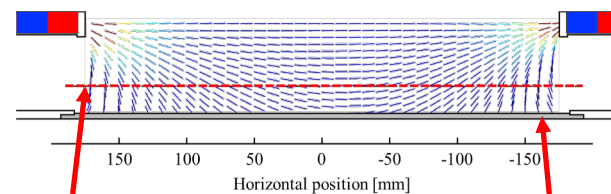
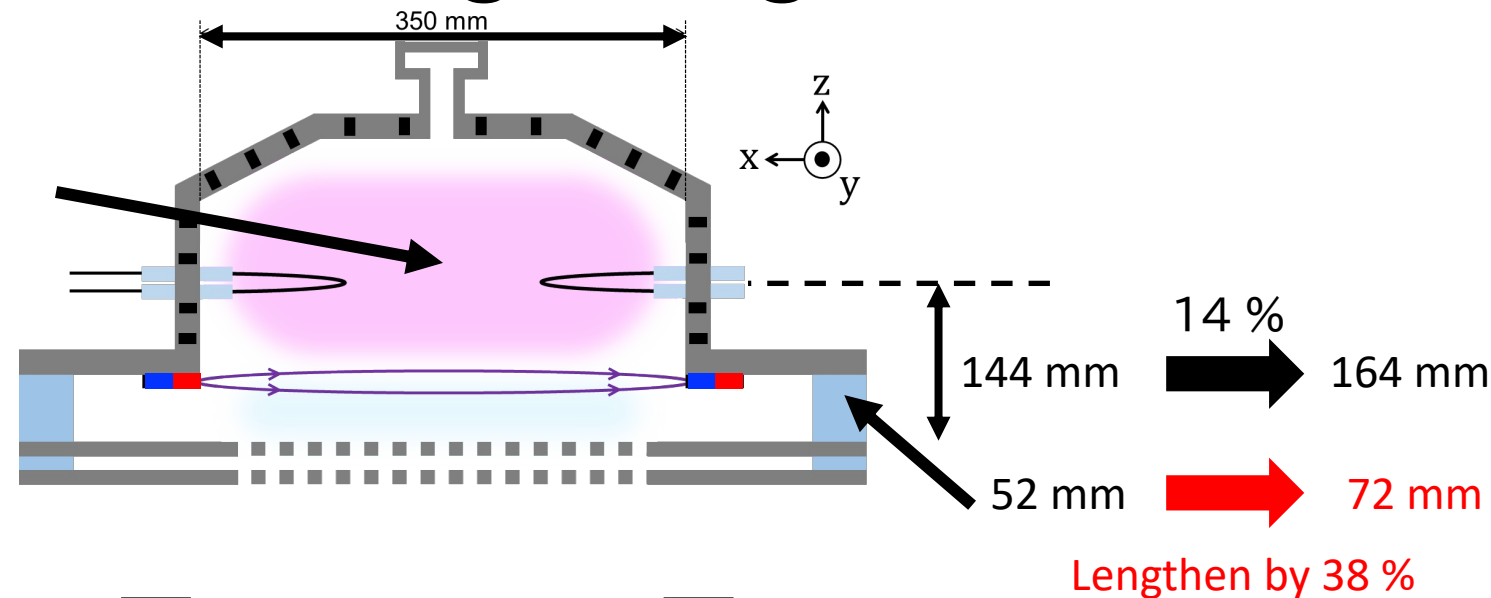


Local n_- dependence on local n_+ can be explained by assuming positive ion being dominant negative ion particle.

Reduction of n_+ with maintaining energetic atom flux

Energetic atom having potential of being negative ion parent particle should be generated in plasma generation region with high T_e by Frank-Condon process.

Energetic atom flux to PG is not affected by the filter field.



Original PG position

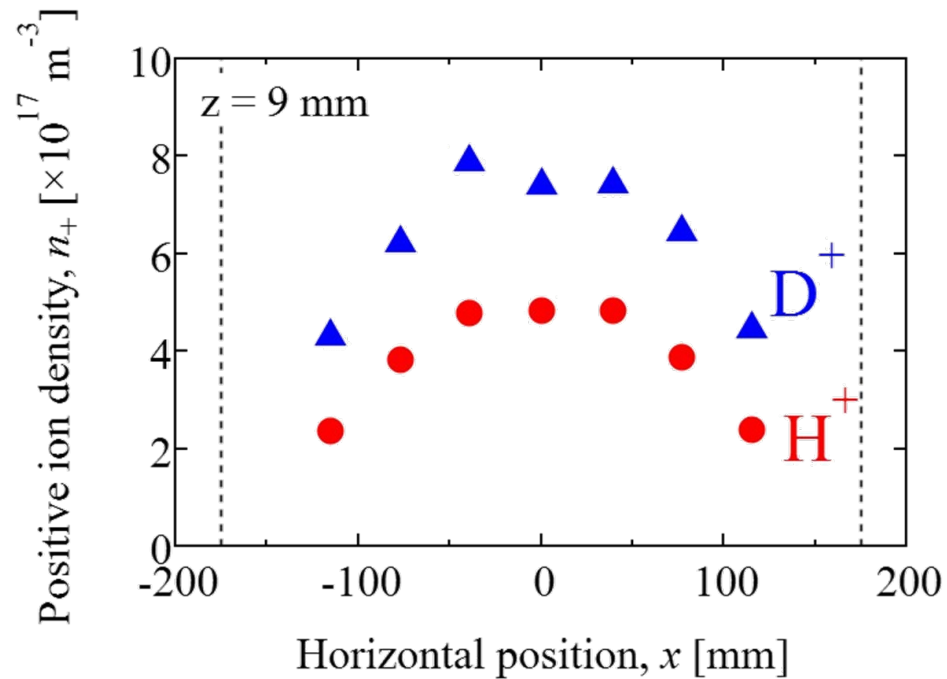
PG position after setting thicker bias insulator

Reduction of n_+ near PG with maintaining energetic atom flux can be conducted.

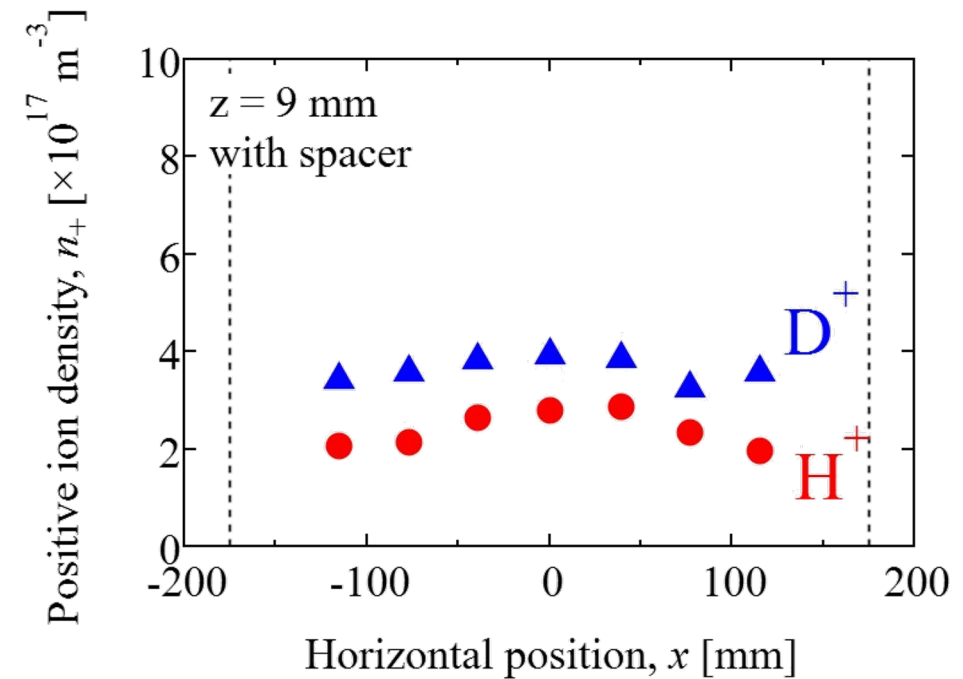
n_+ , actually plasma density, is expected to decrease in the vicinity of PG.

Positive ion density profile with thicker bias flange

Original bias insulator



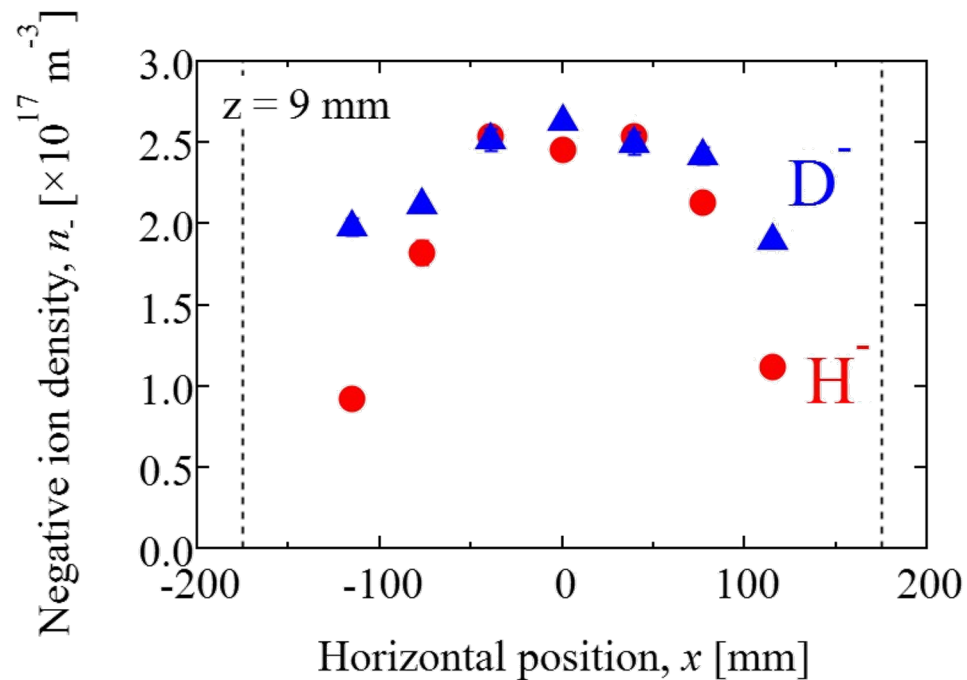
Thicker bias insulator



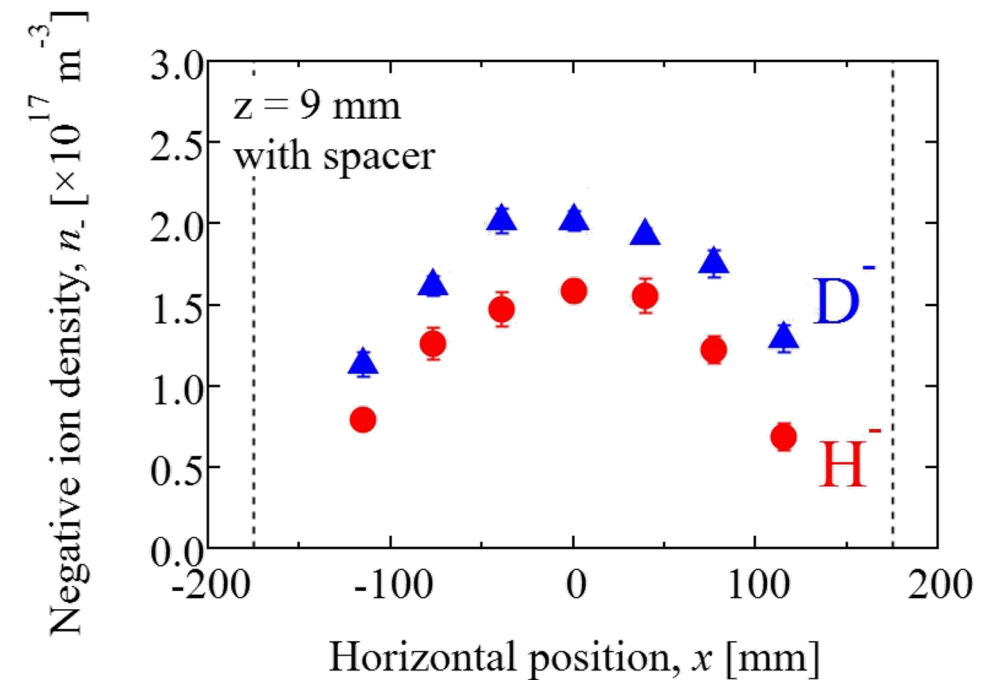
Both H and D positive ions density decreased in the expectation.

Negative ion density profile with thicker bias flange

Original bias insulator

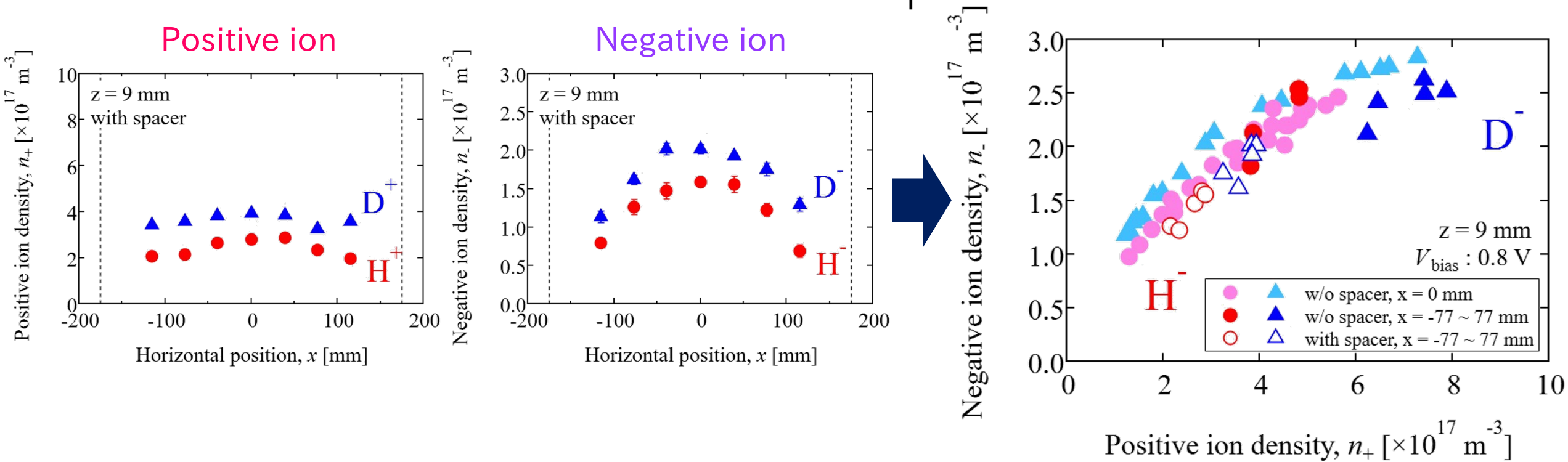


Thicker bias insulator



- Both H and D negative ions density decreased as well as positive ion density. Central density decreased by $\sim 25\%$, which corresponds to expected energetic atom flux density reduction by 14% further distance of filament (plasma production area) from the PG comparing with original.
- But** both shapes of H and D negative ion profile were peak in thicker bias insulator case.

Relation between n_- and n_+



With the thicker bias insulator, the relation between n_- and n_+ is the same as other data.

Data in various experiment agree with the positive ion being the dominant parent particle for the surface produced negative ion.

Summary

Mutual neutralization is a main process of negative ion destruction.

- The n_- increase with n_+ degrades in high n_+ .
- Ratios of n_-/n_+ of the isotopes are similar values as a function of n_+ .
- In local area, whose characteristic length is ~ 50 mm, the n_- is limited by the n_+ . This means n_- profile is affected by n_+ profile.

There is no inconsistency in **positive ion as the dominant parent particle** of surface produced negative ion in NIFS-RNIS with condition of 0.3 Pa in H and D operations.